Micropower Precision CMOS Operational Amplifier

AD8500

FEATURES

Supply current: 1 µA maximum
Offset voltage: 1 mV maximum
Single-supply or dual-supply operation
Rail-to-rail input and output
No phase reversal
Unity gain stable

APPLICATIONS

Portable equipment
Remote sensors
Low power filters
Threshold detectors
Current sensing

PIN CONFIGURATION

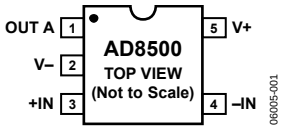


Figure 1. 5-Lead SC70

GENERAL DESCRIPTION

The AD8500 is a low power, precision CMOS op amp featuring a maximum supply current of 1 µA. The AD8500 has a maximum offset voltage of 1 mV and a typical input bias current of 1 pA; it operates rail-to-rail on both the input and output. The AD8500 can operate from a single-supply voltage of +1.8 V to +5.5 V or a dual-supply voltage of ±0.9 V to ±2.75 V.

With its low power consumption, low input bias current, and rail-to-rail input and output, the AD8500 is ideally suited for a variety of battery-powered portable applications. Potential applications include ECGs, pulse monitors, glucose meters, smoke and fire detectors, vibration monitors, and backup battery sensors.

The ability to swing rail-to-rail at both the input and output helps maximize dynamic range and signal-to-noise ratio in systems that operate at very low voltages. The low offset voltage allows the AD8500 to be used in systems with high gain without having excessively large output offset errors, and it provides high accuracy without the need for system calibration.

The AD8500 is fully specified over the industrial temperature range (−40°C to +85°C) and is operational over the extended industrial temperature range (−40°C to +125°C). It is available in a 5-lead, SC70 surface-mount package.

Rev. A

One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106, U.S.A.
Tel: 781.329.4700 **www.analog.com**
Fax: 781.461.3113

TABLE OF CONTENTS

REVISION HISTORY

8/06—Rev. 0 to Rev. A

Updated Format ..... Universal
Changes to Figure 17, Figure 18, and Figure 19 8

4/06—Revision 0: Initial Version

SPECIFICATIONS

ELECTRICAL CHARACTERISTICS

@ V_S = 5 V, V_{CM} = V_S/2, T_A = 25°C, unless otherwise noted.

Table 1.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
INPUT CHARACTERISTICS						
Offset Voltage	V_{OS}	0 V < V_{CM} < 5 V		0.235	1	mV
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$	−40°C < T_A < +85°C		3	10	µV/°C
Input Voltage Range			−0.3		+5.3	V
Input Bias Current	I_B			1	10	pA
		−40°C < T_A < +85°C			100	pA
		−40°C < T_A < +125°C			600	pA
Input Offset Current	I_{OS}			0.5	5	pA
		−40°C < T_A < +85°C			50	pA
		−40°C < T_A < +125°C			100	pA
Common-Mode Rejection Ratio	CMRR	0 V < V_{CM} < 5 V	75	90		dB
		−40°C < T_A < +85°C	70	90		dB
Large Signal Voltage Gain	A_{VO}	0.1 V < V_{OUT} < 4.9 V	98	120		dB
		0.1 V < V_{OUT} < 4.9 V; −40°C < T_A < +85°C	80			dB
Input Capacitance	C_{DIFF}			2		pF
	C_{CM}			4.5		pF
OUTPUT CHARACTERISTICS						
Output Voltage High	V_{OH}	R_{LOAD} = 100 kΩ to GND	4.970	4.995		V
		R_{LOAD} = 10 kΩ to GND	4.900	4.960		V
Output Voltage Low	V_{OL}	R_{LOAD} = 100 kΩ to V_S		0.85	5	mV
		R_{LOAD} = 10 kΩ to V_S		6.5	15	mV
Short-Circuit Current	I_{SC}	V_{OUT} = GND		±5		mA
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	1.8 V < V_S < 5 V	90	110		dB
		−40°C < T_A < +85°C	80			dB
Supply Current/Amplifier	I_{SY}	V_O = V_S/2		0.75	1	µA
		−40°C < T_A < +85°C			1.5	µA
		−40°C < T_A < +125°C			2	µA
DYNAMIC PERFORMANCE						
Slew Rate	SR			0.004		V/µs
Gain Bandwidth Product	GBP			7		kHz
Phase Margin	$Ø_O$			60		Degrees
NOISE PERFORMANCE						
Peak-to-Peak Noise		0.1 Hz to 10 Hz		6		µV p-p
Voltage Noise Density	e_n	f = 1 kHz		190		nV/√Hz
Current Noise Density	i_n	f = 1 kHz		0.1		pA/√Hz

@ V_S = 1.8 V, V_{CM} = V_S/2, T_A = 25°C, unless otherwise noted.

Table 2.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
INPUT CHARACTERISTICS						
Offset Voltage	V_{OS}	0 V < V_{CM} < 1.8 V		0.235	1	mV
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$	−40°C < T_A < +85°C		3.5	12	µV/°C
Input Voltage Range			−0.3		+2.1	V
Input Bias Current	I_B			1	10	pA
		−40°C < T_A < +85°C			100	pA
		−40°C < T_A < +125°C			600	pA
Input Offset Current	I_{OS}			0.5	5	pA
		−40°C < T_A < +85°C			50	pA
		−40°C < T_A < +125°C			100	pA
Common-Mode Rejection Ratio	CMRR	0 V < V_{CM} < 1.8 V	65	85		dB
		−40°C < T_A < +85°C	60	83		dB
Large Signal Voltage Gain	A_{VO}	0.1 V < V_{OUT} < 1.7 V	88	115		dB
		0.1 V < V_{OUT} < 1.7 V; −40°C < T_A < +85°C	70			dB
Input Capacitance	C_{DIFF}			2		pF
	C_{CM}			4.5		pF
OUTPUT CHARACTERISTICS						
Output Voltage High	V_{OH}	R_{LOAD} = 100 kΩ to GND	1.790	1.798		V
		R_{LOAD} = 10 kΩ to GND	1.760	1.783		V
Output Voltage Low	V_{OL}	R_{LOAD} = 100 kΩ to V_S		0.70	5	mV
		R_{LOAD} = 10 kΩ to V_S		5	15	mV
Short-Circuit Current	I_{SC}			±2		mA
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	1.8 V < V_S < 5 V	90	110		dB
		−40°C < T_A < +85°C	80			dB
Supply Current/Amplifier	I_{SY}	V_O = V_S/2		0.65	1	µA
		−40°C < T_A < +85°C			1.5	µA
		−40°C < T_A < +125°C			2	µA
DYNAMIC PERFORMANCE						
Slew Rate	SR			0.004		V/µs
Gain Bandwidth Product	GBP			7		kHz
Phase Margin	$Ø_O$			60		Degrees
NOISE PERFORMANCE						
Peak-to-Peak Noise		0.1 Hz to 10 Hz		6		µV p-p
Voltage Noise Density	e_n	f = 1 kHz		190		nV/√Hz
Current Noise Density	i_n	f = 1 kHz		0.1		pA/√Hz

ABSOLUTE MAXIMUM RATINGS

T_A = 25°C, unless otherwise noted.

Table 3.

Parameter	Rating
Supply Voltage	6 V
Input Voltage	V_{SS} − 0.4 V to V_{DD} + 0.4 V
Differential Input Voltage	±6 V
Output Short-Circuit Duration to GND	Indefinite
Storage Temperature Range	−65°C to +150°C
Operating Temperature Range	−40°C to +125°C
Junction Temperature Range	−65°C to +150°C
Lead Temperature (Soldering, 60 sec)	300°C

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Absolute maximum ratings apply at 25°C, unless otherwise noted.

THERMAL RESISTANCE

θ_{JA} is specified for the worst-case conditions, that is, a device soldered in a circuit board for surface-mount packages.

Table 4. Thermal Characteristics

Package Type	θ_{JA}	θ_{JC}	Unit
5-Lead SC70 (KS-5)	376	126	°C/W

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.

TYPICAL PERFORMANCE CHARACTERISTICS

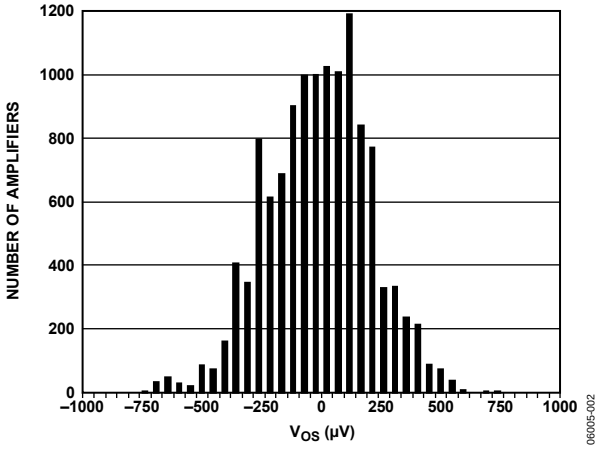


Figure 2. Input Offset Voltage Distribution
(0 V < V_{CM} < 5.0 V)

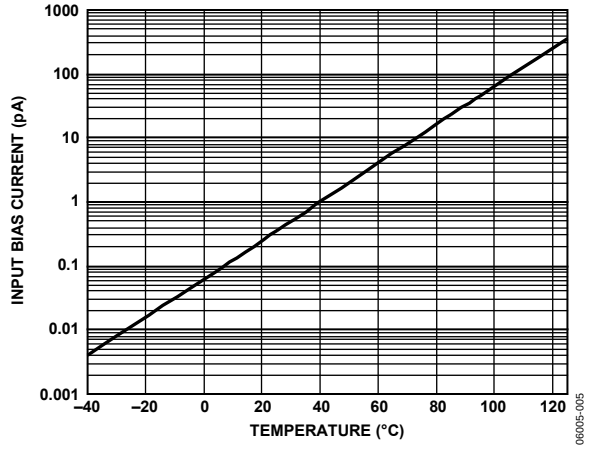


Figure 5. Input Bias Current vs. Temperature
(V_S = 1.8 V and 5.0 V)

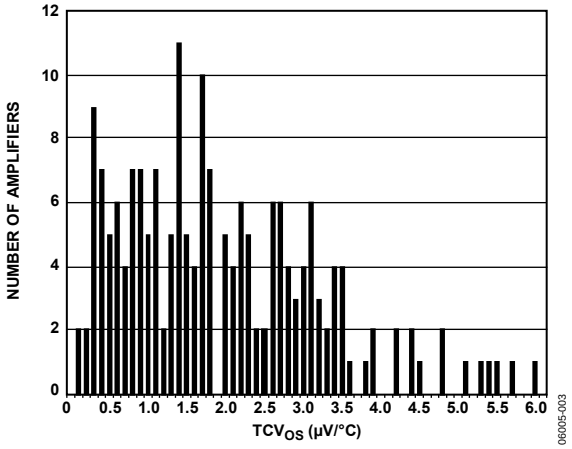


Figure 3. Input Offset Voltage Drift Distribution
(–40°C < T_A < +85°C)

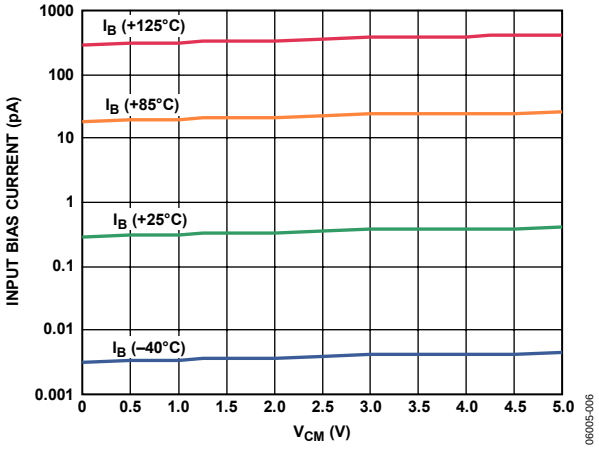


Figure 6. Input Bias Current vs. Common-Mode Voltage

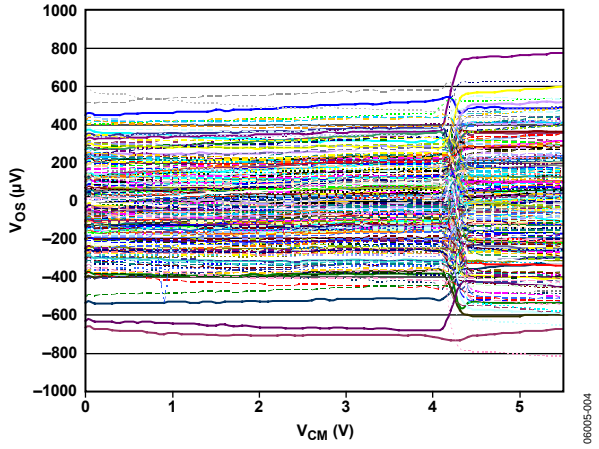


Figure 4. Input Offset Voltage vs. Common-Mode Voltage

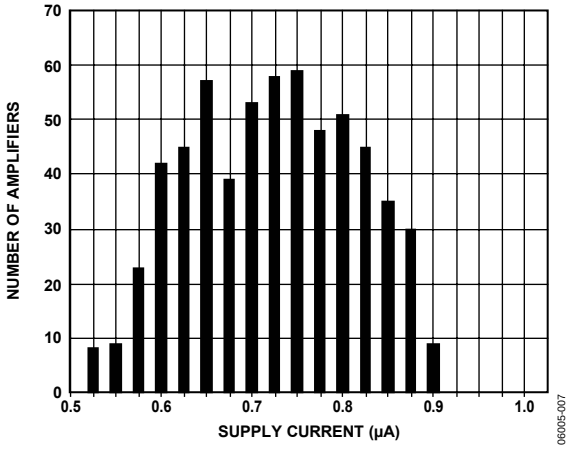


Figure 7. Supply Current Distribution

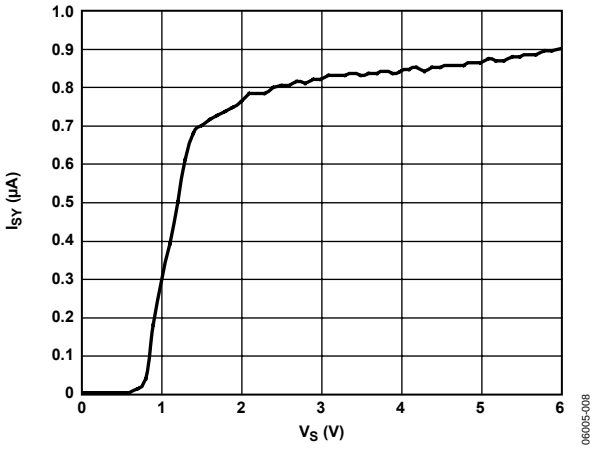


Figure 8. Supply Current vs. Supply Voltage

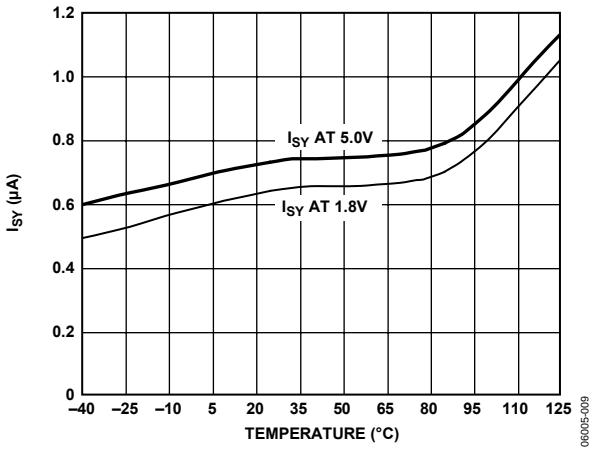


Figure 9. Supply Current vs. Temperature

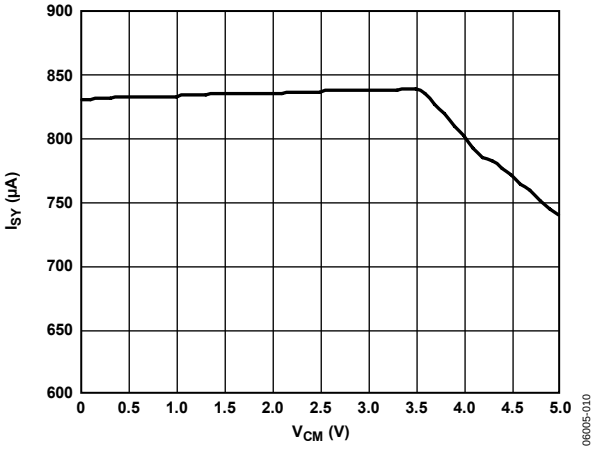


Figure 10. Supply Current vs. Input Common-Mode Voltage

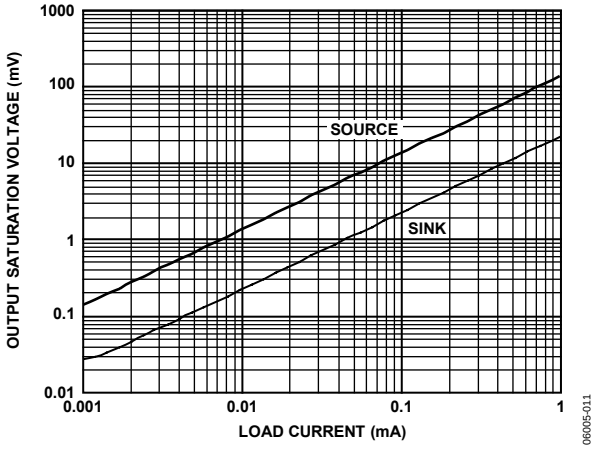


Figure 11. Output Saturation Voltage vs. Load Current

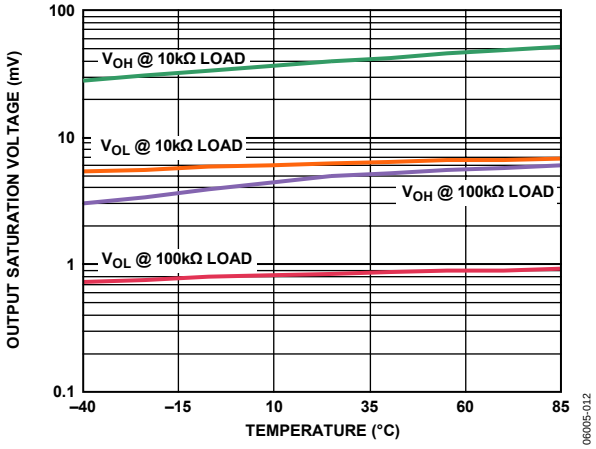


Figure 12. Output Saturation Voltage vs. Temperature

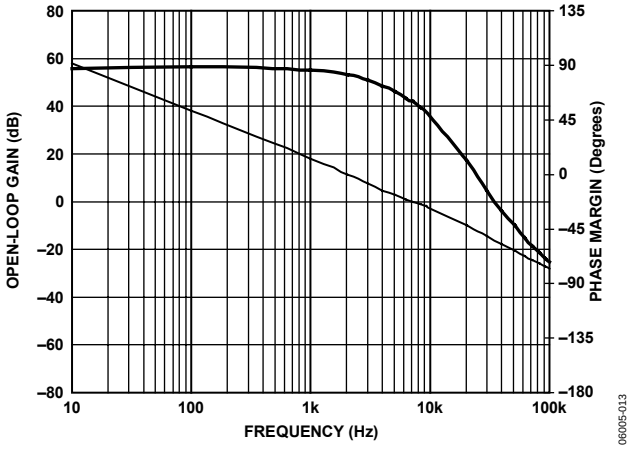


Figure 13. Open-Loop Gain and Phase vs. Frequency

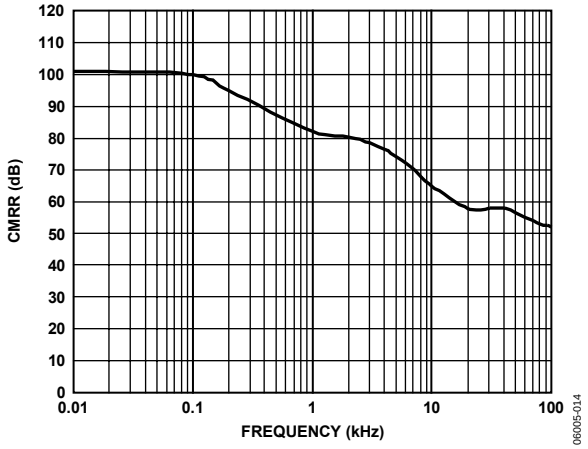


Figure 14. CMRR vs. Frequency

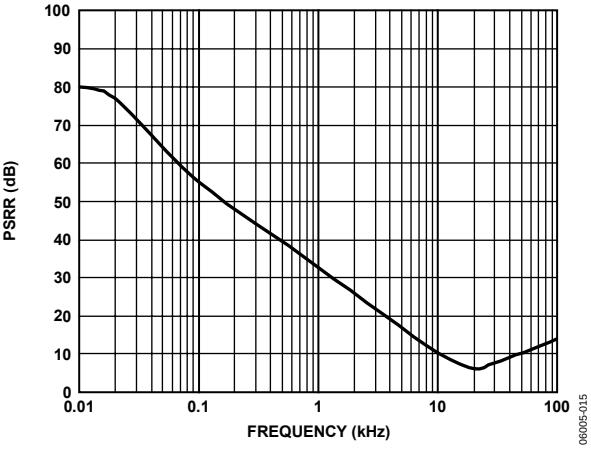


Figure 15. PSRR vs. Frequency

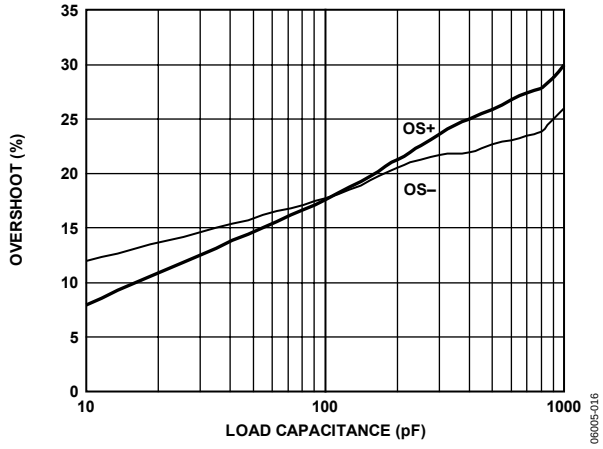


Figure 16. Small Signal Overshoot vs. Load Capacitance

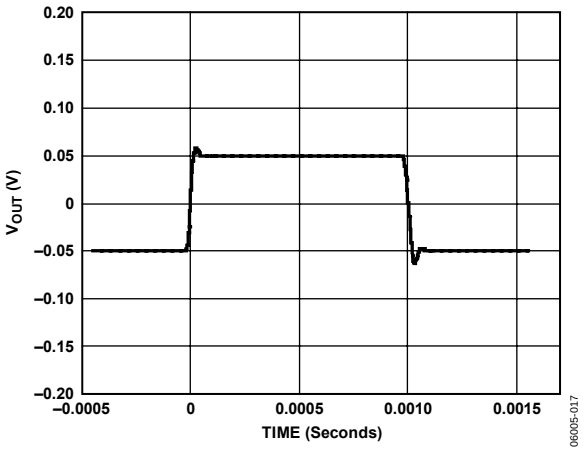


Figure 17. Small Signal Transient Response (No Load)

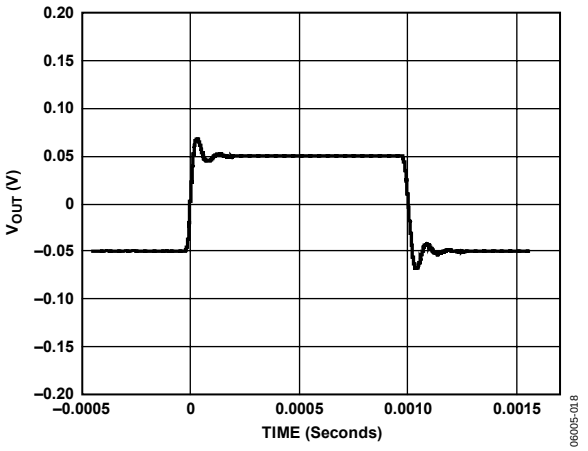


Figure 18. Small Signal Transient Response (100 pF Load Capacitance)

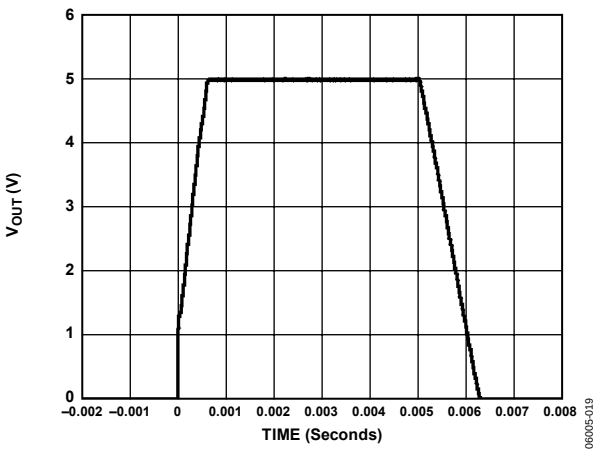


Figure 19. Large Signal Transient Response (No Load)

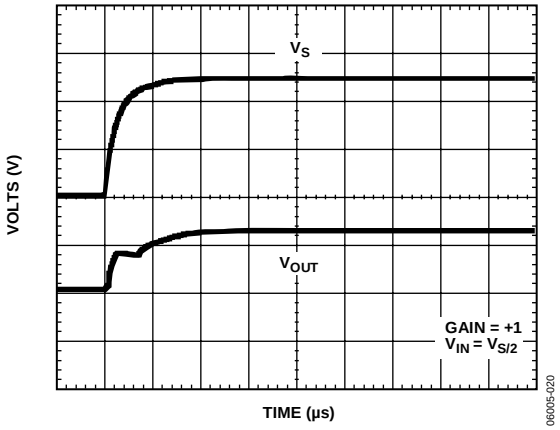


Figure 20. Turn-On Transient Response

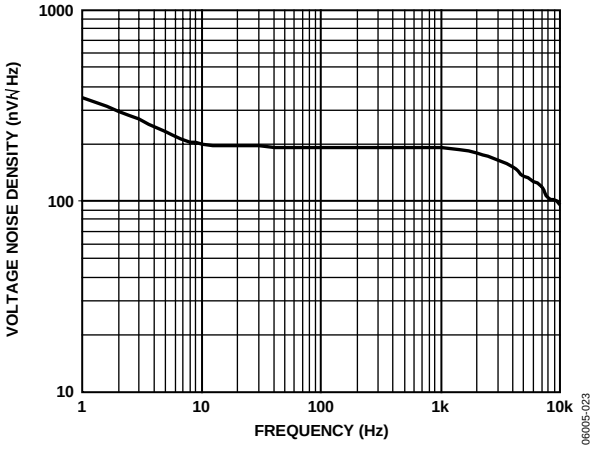


Figure 23. Voltage Noise Density
(V_S = 1.8 V and 5.0 V)

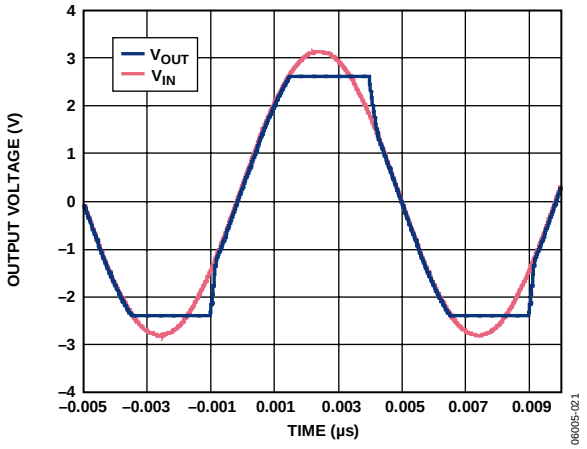


Figure 21. No Phase Reversal

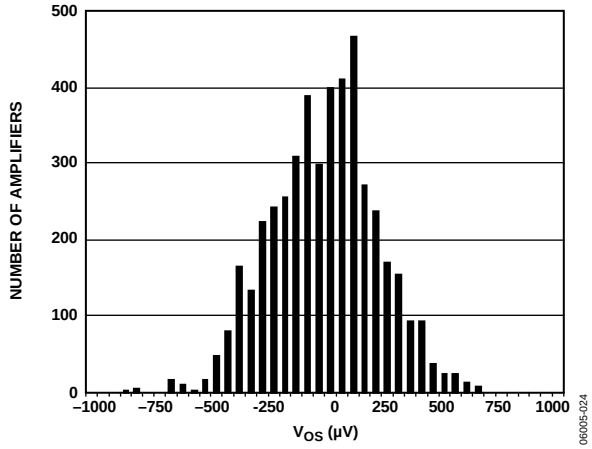


Figure 24. Input Offset Voltage Distribution
($0 V < V_{CM} < 1.8 V$)

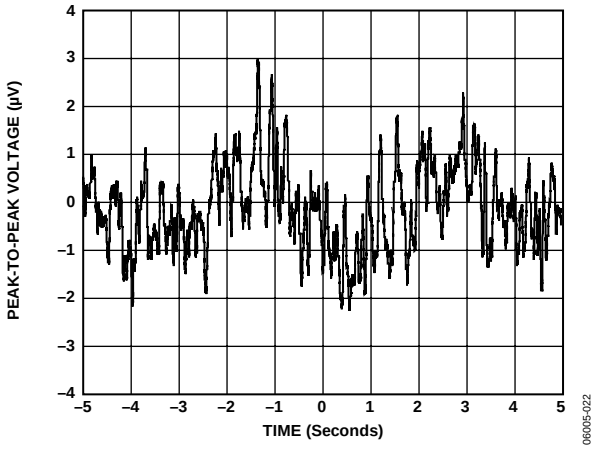


Figure 22. 0.1 Hz to 10 Hz Input Voltage Noise
(V_S = 5 V and 1.8 V)

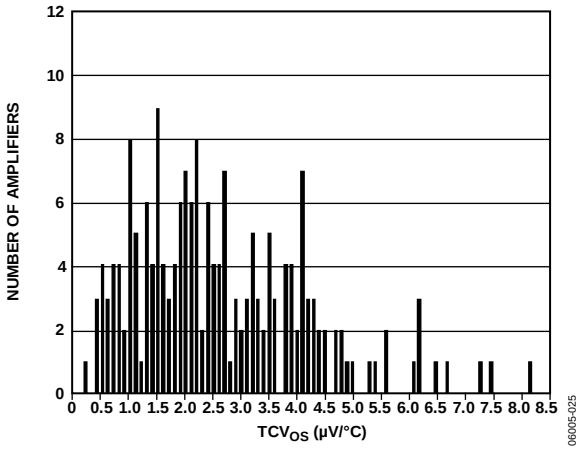


Figure 25. Input Offset Voltage Drift Distribution
($-40°C < T_A < +85°C$)

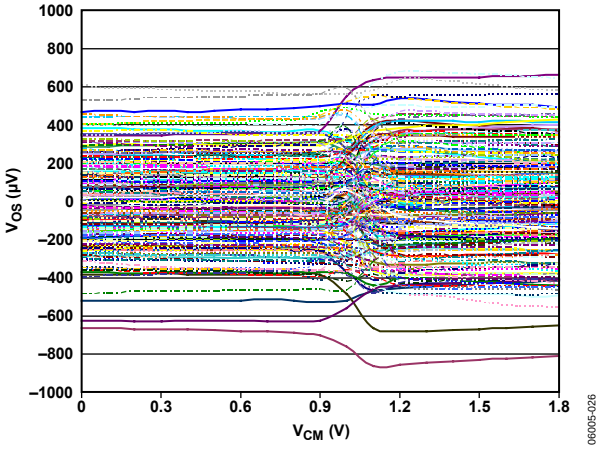


Figure 26. Input Offset Voltage vs. Input Common-Mode Voltage

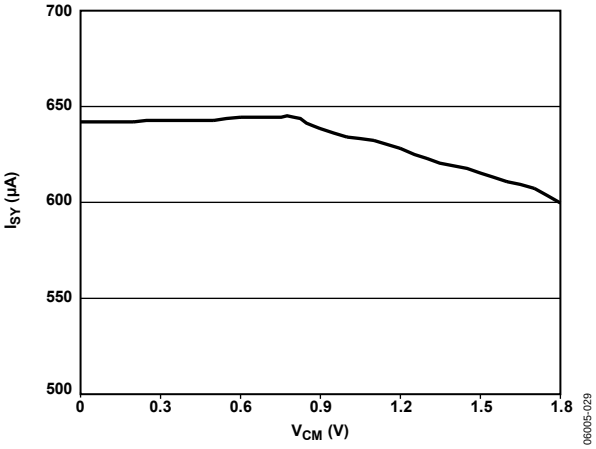


Figure 29. Supply Current vs. Input Common-Mode Voltage

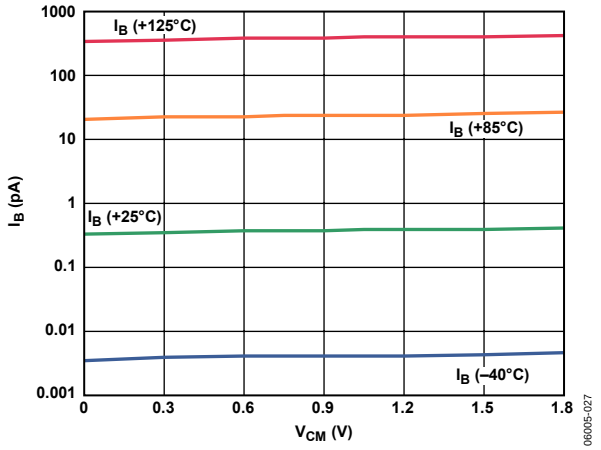


Figure 27. Input Bias Current vs. Input Common-Mode Voltage

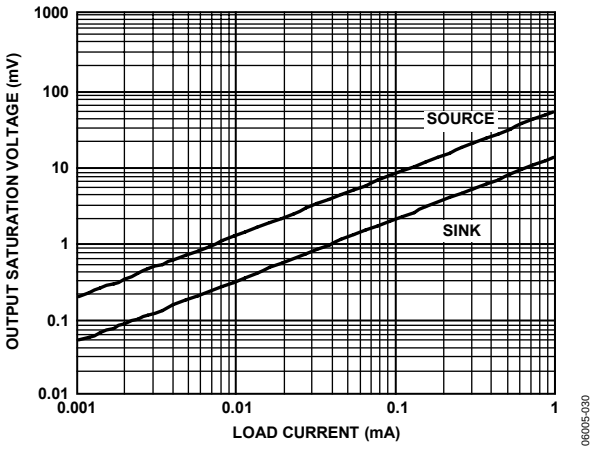


Figure 30. Output Saturation Voltage vs. Load Current

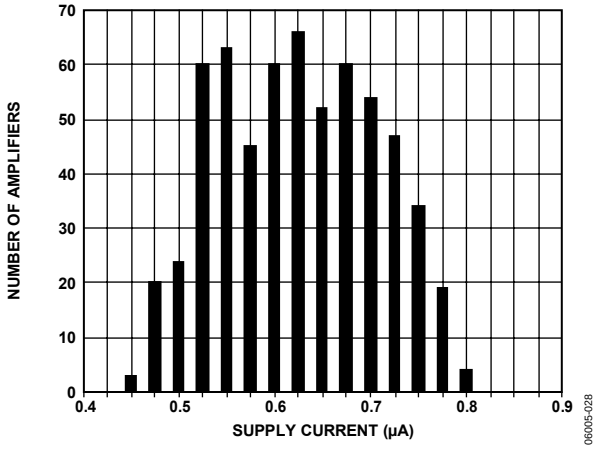


Figure 28. Supply Current Distribution

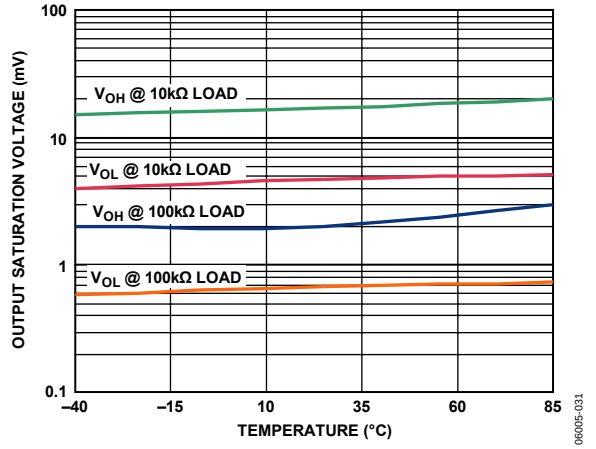


Figure 31. Output Saturation Voltage vs. Temperature

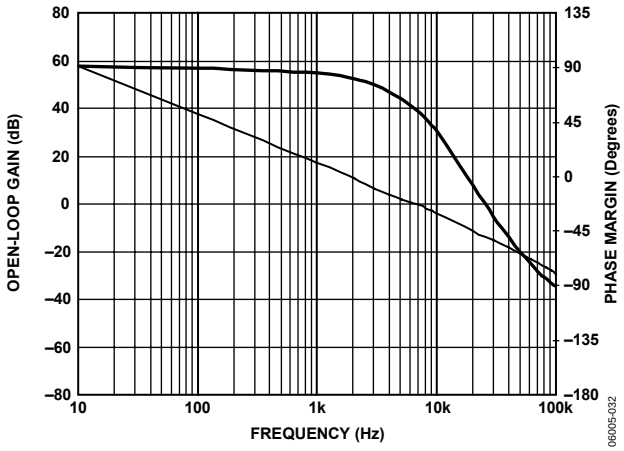


Figure 32. Open-Loop Gain and Phase vs. Frequency

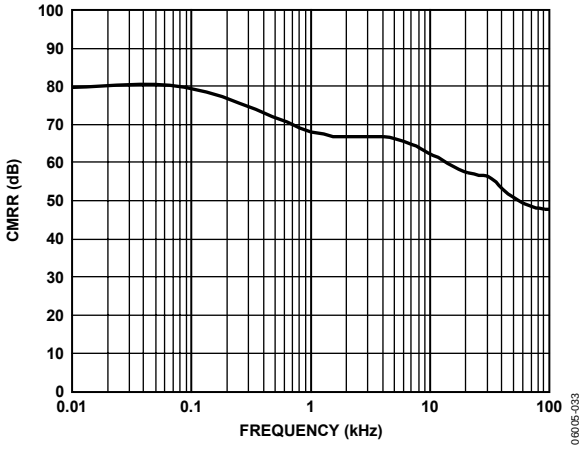


Figure 33. CMRR vs. Frequency

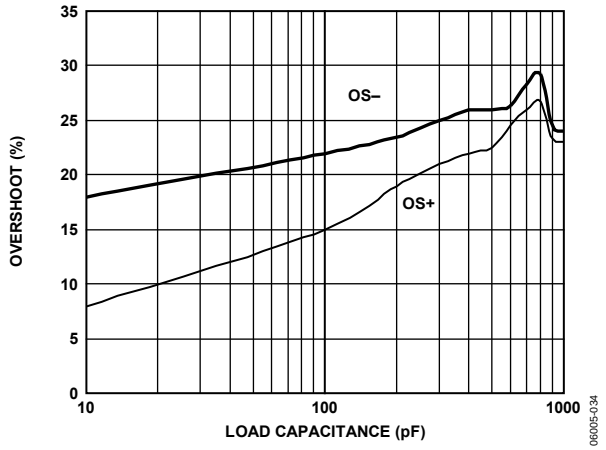


Figure 34. Small Signal Overshoot vs. Load Capacitance

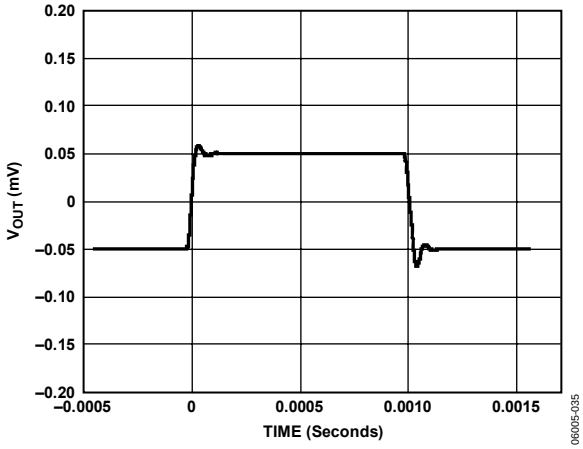


Figure 35. Small Signal Transient Response (No Load)

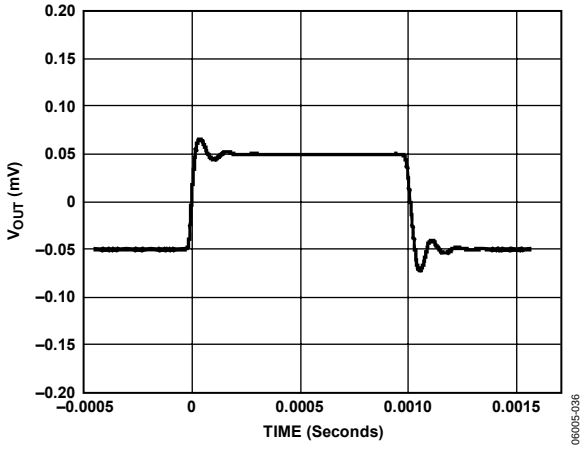


Figure 36. Small Signal Transient Response (100 pF Load Capacitance)

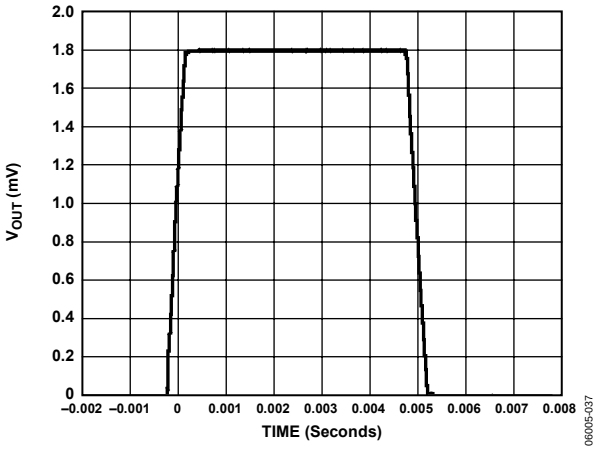
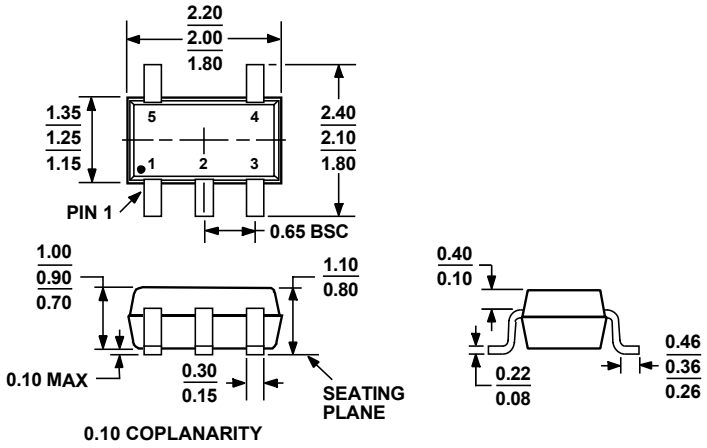


Figure 37. Large Signal Transient Response (No Load)

OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-203-AA

Figure 38. 5-Lead Thin Shrink Small Outline Transistor Package [SC70]
(KS-5)
Dimensions shown in millimeters

ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option	Branding
AD8500AKSZ-R2[1]	−40°C to +125°C	5-Lead SC70	KS-5	A0F
AD8500AKSZ-REEL[1]	−40°C to +125°C	5-Lead SC70	KS-5	A0F
AD8500AKSZ-REEL7[1]	−40°C to +125°C	5-Lead SC70	KS-5	A0F

[1] Z = Pb-free part.

D06005-0-8/06(A)